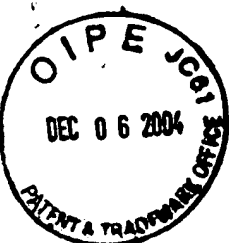


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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: Yeo, *et al.* Docket No.: TSM03-0511
Serial No.: 10/669,395 Art Unit: 2811
Filed: September 24, 2003 Examiner: Gebremariam, Samuel A.
For: Multiple-Gate Transistors Formed on Bulk Substrates

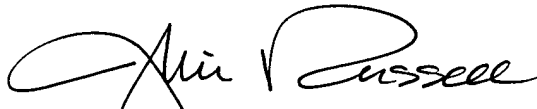
Certificate of Mailing via First Class Mail (37 C.F.R. § 1.8(a))

Date of Deposit: December 1, 2004

I hereby certify that the below listed correspondence is being deposited with the United States Postal Service on the date indicated above as first class mail in an envelope addressed to: Mail Stop Amendment, Commissioner for Patents, P. O. Box 1450, Alexandria, VA 22313-1450.

Certificate of Mailing via First Class Mail (1 page)
Amendment (13 pages)
One (1) Sheet Replacement Drawings
Return Postcard

Respectfully submitted,


Julie Russell
Legal Assistant

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Mail Stop: Amendment
Commissioner for Patents
P. O. Box 1450
Alexandria, VA 22313-1450

AMENDMENT

Dear Sir:

The following amendments and remarks are presented in response to the Examiner's Office Action mailed September 9, 2004. Please amend the above-referenced application as follows.